

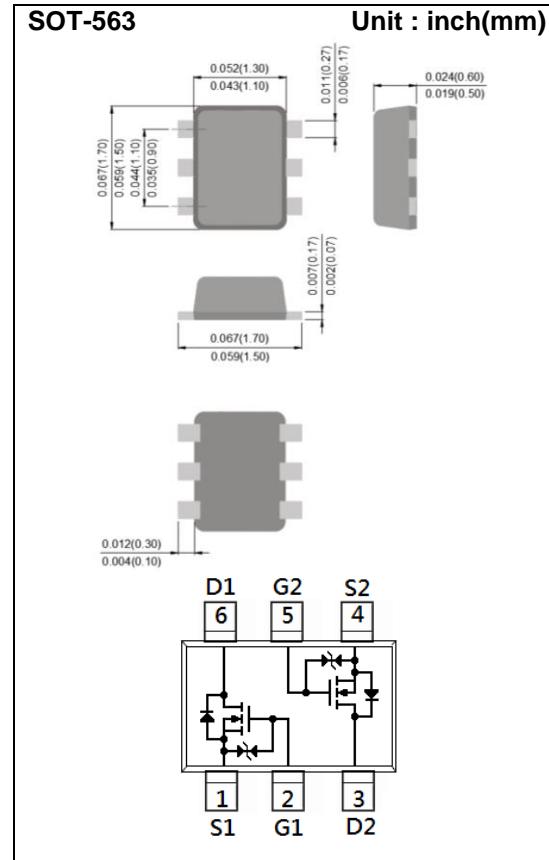
# PJX138L

## 60V N-Channel Enhancement Mode MOSFET

**Voltage**    **60 V**    **Current**    **160 mA**

### Features

- RDS(ON) , VGS@10V, ID@160mA<4.2Ω
- RDS(ON) , VGS@4.5V, ID@100mA<5Ω
- RDS(ON) , VGS@2.5V, ID@50mA<7Ω
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



### Mechanical Data

- Case: SOT-563 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0026 grams
- Marking: X8L

### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	160	mA
Pulsed Drain Current	$I_{DM}$	800	mA
Power Dissipation	$T_A=25^\circ\text{C}$	223	mW
	Derate above 25°C	1.8	mW/°C
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>	$R_{\theta JA}$	560	°C/W

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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	60	-	-	V
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	0.8	1.2	1.5	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=160\text{mA}$	-	2.5	4.2	$\Omega$
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=100\text{mA}$	-	2.8	5	
		$\text{V}_{\text{GS}}=2.5\text{V}, \text{I}_D=50\text{mA}$	-	3.7	7	
		$\text{V}_{\text{GS}}=1.8\text{V}, \text{I}_D=10\text{mA}$	-	12	-	
Zero Gate Voltage Drain Current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}}=60\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	0.01	1	$\mu\text{A}$
Gate-Source Leakage Current	$\text{I}_{\text{GSS}}$	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	$\pm 1.0$	$\pm 10$	$\mu\text{A}$
<b>Dynamic</b> <sup>(Note 4)</sup>						
Total Gate Charge	$\text{Q}_g$	$\text{V}_{\text{DS}}=15\text{V}, \text{I}_D=160\text{mA}, \text{V}_{\text{GS}}=4.5\text{V}^{(\text{Note 1,2})}$	-	0.7	-	nC
Gate-Source Charge	$\text{Q}_{\text{gs}}$		-	0.33	-	
Gate-Drain Charge	$\text{Q}_{\text{gd}}$		-	0.2	-	
Input Capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}}=15\text{V}, \text{V}_{\text{GS}}=0\text{V}, f=1.0\text{MHZ}$	-	15	-	pF
Output Capacitance	$\text{C}_{\text{oss}}$		-	8.4	-	
Reverse Transfer Capacitance	$\text{Crss}$		-	4.2	-	
Turn-On Delay Time	$\text{td}_{(\text{on})}$	$\text{V}_{\text{DD}}=10\text{V}, \text{I}_D=160\text{mA}, \text{V}_{\text{GS}}=10\text{V}, \text{R}_G=6\Omega^{(\text{Note 1,2})}$	-	7	-	ns
Turn-On Rise Time	$\text{tr}$		-	22	-	
Turn-Off Delay Time	$\text{td}_{(\text{off})}$		-	21	-	
Turn-Off Fall Time	$\text{tf}$		-	25	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$\text{I}_s$	---	-	-	160	$\text{mA}$
Diode Forward Voltage	$\text{V}_{\text{SD}}$	$\text{I}_s=160\text{mA}, \text{V}_{\text{GS}}=0\text{V}$	-	0.8	1.1	V

### NOTES :

1. Pulse width $\leq 300\text{us}$ , Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $\text{R}_{\text{QJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
4. Guaranteed by design, not subject to production testing.

# PJX138L

## TYPICAL CHARACTERISTIC CURVES

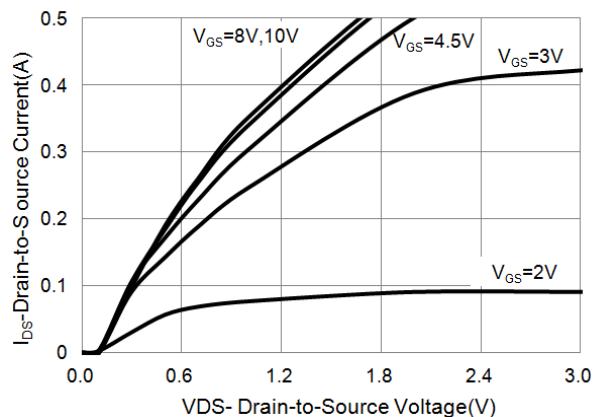


Fig.1 On-Region Characteristics

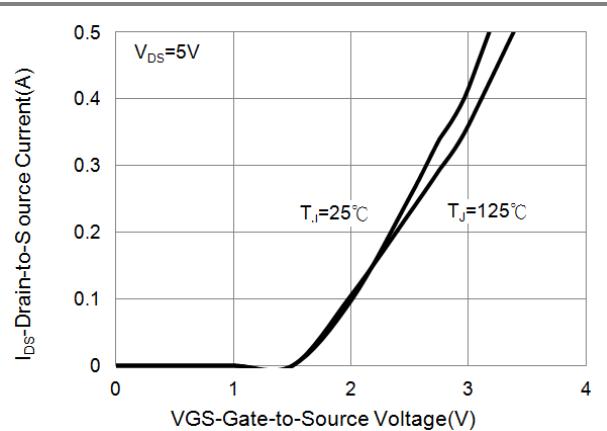


Fig.2 Transfer Characteristics

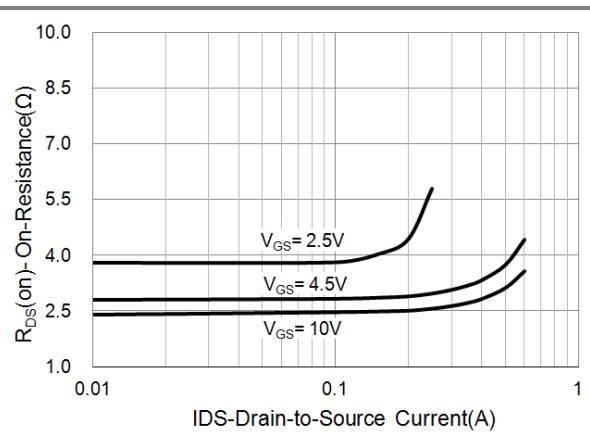


Fig.3 On-Resistance vs. Drain Current

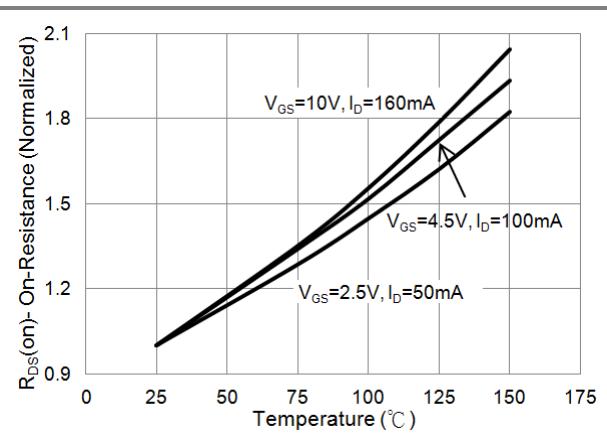


Fig.4 On-Resistance vs. Junction temperature

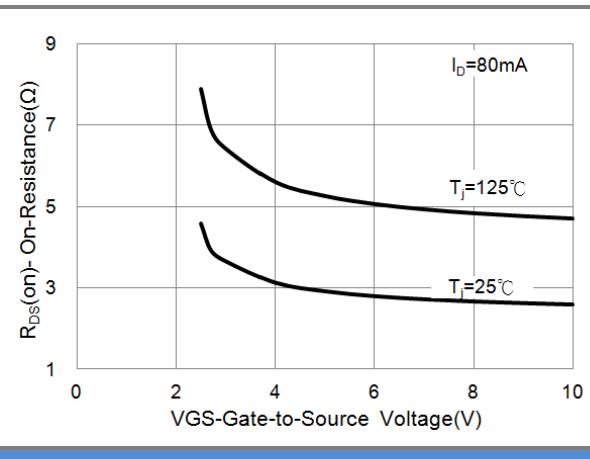


Fig.5 On-Resistance Variation with VGS.

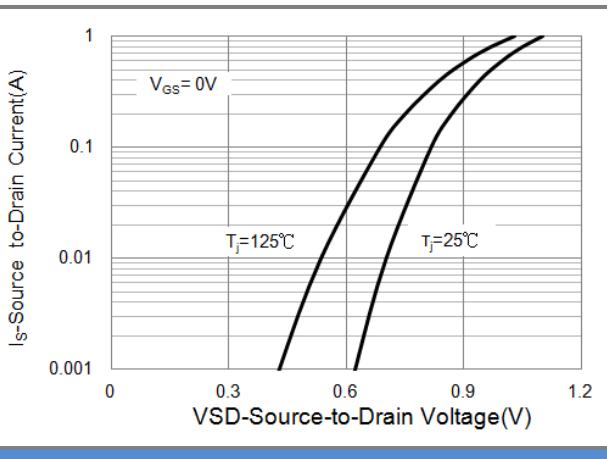
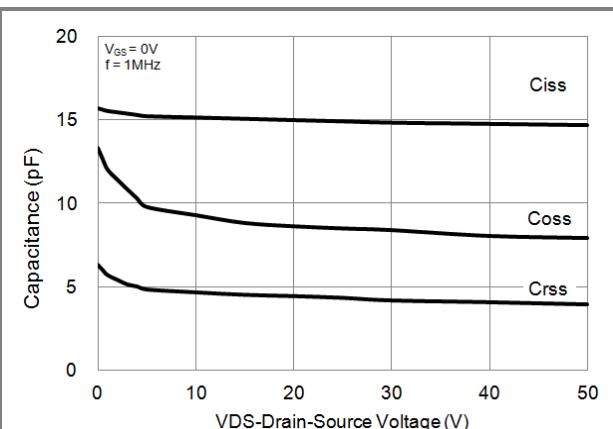
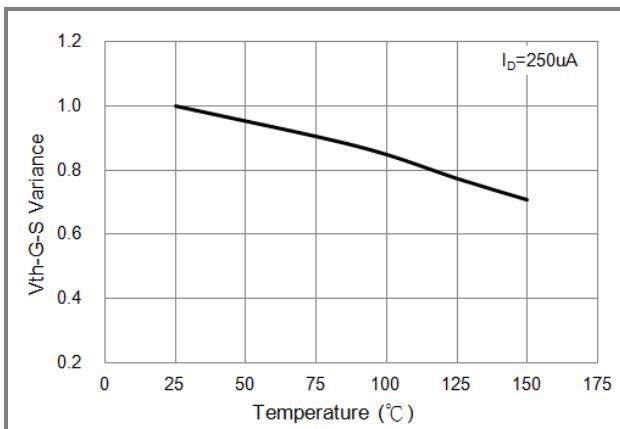
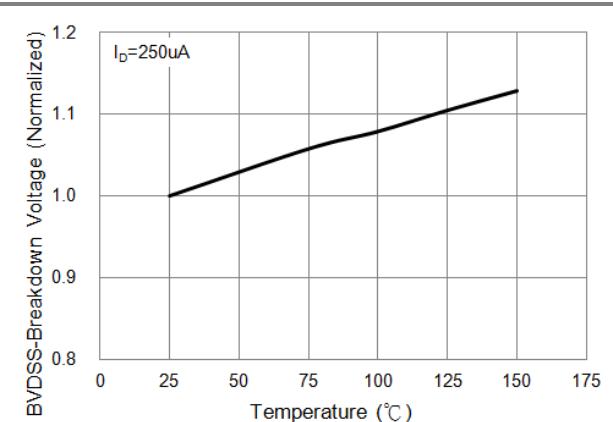
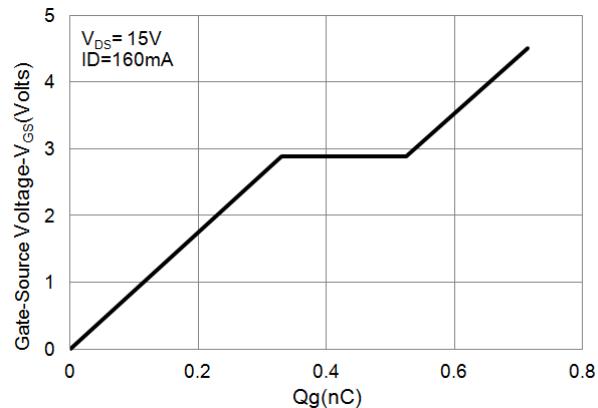


Fig.6 Body Diode Characteristics

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## TYPICAL CHARACTERISTIC CURVES

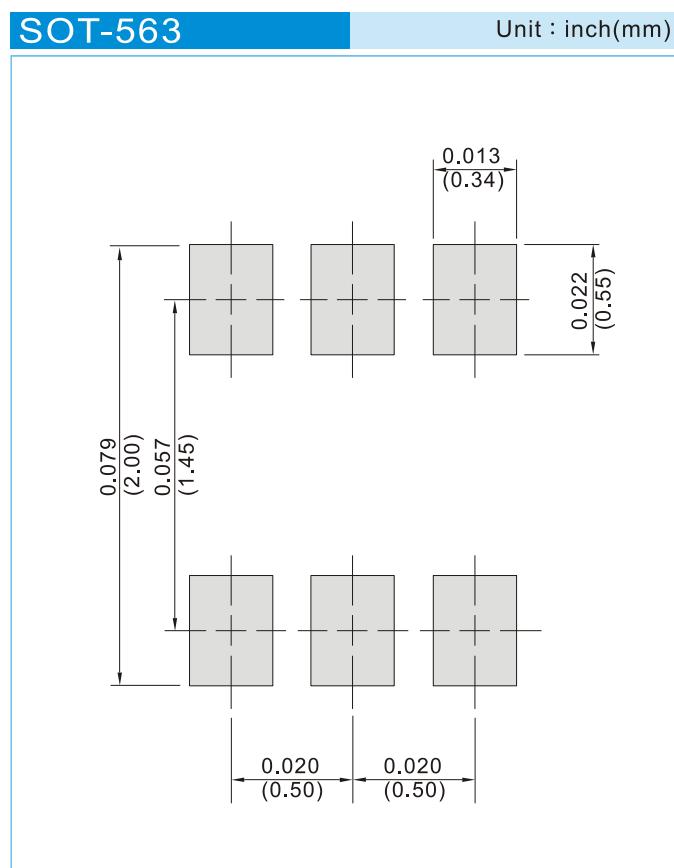


# PJX138L

## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJX138L	SOT-563	4K pcs / 7" reel	X8L
PJX138L	SOT-563	10K pcs / 13" reel	X8L

## Mounting Pad Layout



## PJX138L

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